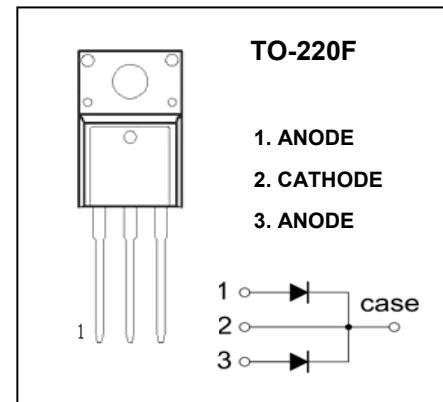


MBRF3030CT, 35CT, 40CT, 45CT, 50CT, 60CT

SCHOTTKY BARRIER RECTIFIER

FEATURES

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- Low Power Loss, High Efficiency
- High Surge Capability
- High Current Capability and Low Forward Voltage Drop
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications



MAXIMUM RATINGS ($T_a=25^\circ\text{C}$ unless otherwise noted)

Symbol	Parameter	Value						Unit
		MBR 3030CT	MBR 3035CT	MBR 3040CT	MBR 3045CT	MBR 3050CT	MBR 3060CT	
V_{RRM}	Peak repetitive reverse voltage							
V_{RWM}	Working peak reverse voltage	30	35	40	45	50	60	V
V_R	DC blocking voltage							
$V_{R(RMS)}$	RMS reverse voltage	21	24.5	28	31.5	35	42	V
I_o	Average rectified output current@ $T_c=100^\circ\text{C}$				30			A
I_{FSM}	Non-Repetitive peak forward surge current 8.3ms half sine wave				200			A
P_D	Power dissipation				2			W
$R_{\theta JA}$	Thermal resistance from junction to ambient				50			$^\circ\text{C/W}$
T_j	Junction temperature				125			$^\circ\text{C}$
T_{stg}	Storage temperature				-55~+150			$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS ($T_a=25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Device	Test conditions	Min	Typ	Max	Unit
Reverse voltage	$V_{(\text{BR})}$	MBR3030CT	$I_R=1\text{mA}$	30			V
		MBR3035CT		35			
		MBR3040CT		40			
		MBR3045CT		45			
		MBR3050CT		50			
		MBR3060CT		60			
Reverse current	I_R	MBR3030CT	$V_R=30\text{V}$				mA
		MBR3035CT	$V_R=35\text{V}$				
		MBR3040CT	$V_R=40\text{V}$				
		MBR3045CT	$V_R=45\text{V}$				
		MBR3050CT	$V_R=50\text{V}$				
		MBR3060CT	$V_R=60\text{V}$				
Forward voltage	V_{F1}	MBR3030CT-3045CT	$I_F=15\text{A}$			0.7	V
		MBR3050CT,3060CT				0.8	
	V_{F2}^*	MBR3030CT-3045CT	$I_F=30\text{A}$			0.84	V
		MBR3050CT,3060CT				0.95	
Typical total capacitance	C_{tot}	MBR3030CT-3045CT	$V_R=4\text{V}, f=1\text{MHz}$		450		pF
		MBR3050CT,3060CT			400		

*Pulse test: pulse width $\leq 300\mu\text{s}$, duty cycle $\leq 2.0\%$.